

QUADRUPLE DIFFERENTIAL LINE DRIVER

Check for Samples: AM26C31

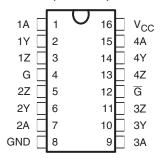
FEATURES

- Meets or Exceeds the Requirements of TIA/EIA-422-B and ITU Recommendation V.11
- Low Power, I_{CC} = 100 µA Typ
- Operates From a Single 5-V Supply
- High Speed, t_{PLH} = t_{PHL} = 7 ns Typ
- Low Pulse Distortion, t_{sk(p)} = 0.5 ns Typ
- High Output Impedance in Power-Off Conditions
- Improved Replacement for AM26LS31
- · Available in Q-Temp Automotive
 - High-Reliability Automotive Applications
 - Configuration Control/Print Support
 - Qualification to Automotive Standards

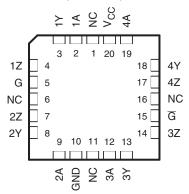
DESCRIPTION/ORDERING INFORMATION

The AM26C31 is a differential line driver with complementary outputs, designed to meet the requirements of TIA/EIA-422-B and ITU (formerly CCITT). The 3-state outputs have high-current capability for driving balanced lines, such as twisted-pair or parallel-wire transmission lines, and they provide the high-impedance state in the power-off condition. The enable functions are common to all four drivers and offer the choice of an active-high (G) or active-low (\overline{G}) enable input. BiCMOS circuitry reduces power consumption without sacrificing speed.

AM26C31M...J OR W PACKAGE AM26C31Q...D PACKAGE AM26C31C...D, DB, OR NS PACKAGE AM26C31I...D, DB, N, NS, OR PW PACKAGE (TOP VIEW)



AM26C31M...FK PACKAGE (TOP VIEW)



NC - No internal connection

The AM26C31C is characterized for operation from 0°C to 70°C, the AM26C31I is characterized for operation from -40°C to 85°C, the AM26C31Q is characterized for operation over the automotive temperature range of -40°C to 125°C, and the AM26C31M is characterized for operation over the full military temperature range of -55°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

T _A	P.A	ACKAGE ⁽¹⁾ (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP (N)	Tube of 25	AM26C31CN	AM26C31CN
	COIC (D)	Tube of 40	AM26C31CD	AM200240
0°C to 70°C	SOIC (D)	Reel of 2500	AM26C31CDR	AM26C31C
	SOP (NS)	Reel of 2000	AM26C31CNSR	26C31
	SSOP (DB)	Reel of 2000	AM26C31CDBR	26C31
	PDIP (N)	Tube of 25	AM26C31IN	AM26C31IN
	COIC (D)	Tube of 40	AM26C31ID	AM200241
40°C += 05°C	SOIC (D)	Reel of 2500	AM26C31IDR	AM26C31I
–40°C to 85°C	SOP (NS)	Reel of 2000	AM26C31INSR	26C31I
	SSOP (DB)	Reel of 2000	AM26C31IDBR	26C31I
	TSSOP (PW)	Tube of 90	AM26C31IPW	26C31I
40°C += 405°C	COIC (D)	Tube of 40	AM26C31QD	AM200240D
–40°C to 125°C	SOIC (D)	Reel of 2500	AM26C31QDR	AM26C31QD
	CDIP (J)	Tube of 25	AM26C31MJ	AM26C31MJ
–55°C to 125°C	CFP (W)	Tube of 150	AM26C31MW	AM26C31MW
	LCCC (FK)	Tube of 55	AM26C31MFK	AM26C31MFK

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
 (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

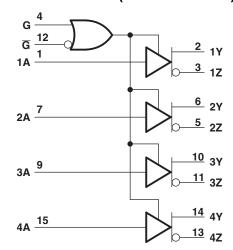
Table 1. FUNCTION TABLE (Each Driver)⁽¹⁾

INPUT	ENA	BLES	OUTPUTS			
Α	G	G	Y	Z		
Н	Н	X	Н	L		
L	Н	X	L	Н		
Н	X	L	Н	L		
L	Х	L	L	Н		
Х	L	Н	Z	Z		

(1) H = High level, L = Low level, X = Irrelevant, Z = High impedance (off)

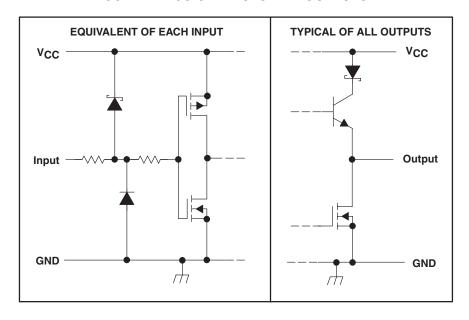


LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the D, DB, J, N, NS, PW, and W packages.

SCHEMATICS OF INPUTS AND OUTPUTS





ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range ⁽²⁾		-0.5	7	V
VI	Input voltage range		-0.5	V _{CC} + 0.5	V
V_{ID}	Differential input voltage range		-14	14	V
Vo	Output voltage range		-0.5	7	
I _{IK} I _{OK}	Input or output clamp current			±20	mA
Io	Output current			±150	mA
	V _{CC} current			200	mA
	GND current		-200		mA
		D package		73	
		DB package		82	
θ_{JA}	Package thermal impedance (3) (4)	N package		67	°C/W
		NS package		64	
		PW package		108	
TJ	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, except differential voltages, are with respect to the network ground terminal.

RECOMMENDED OPERATING CONDITIONS

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		4.5	5	5.5	V
V_{ID}	Differential input voltage			±7		V
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
I_{OH}	High-level output current			-20	mA	
I_{OL}	Low-level output current				20	mA
		AM26C31C	0		70	
_		AM26C31I	-40		85	°C
T _A	Operating free-air temperature	AM26C31Q	-40		125	C
		AM26C31M	-55		125	

Maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.



ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST (CONDITIONS		M26C310 M26C31	-	UNIT
				MIN	TYP ⁽¹⁾	MAX	
V _{OH}	High-level output voltage	$I_O = -20 \text{ mA}$		2.4	3.4		V
V _{OL}	Low-level output voltage	I _O = 20 mA			0.2	0.4	V
V _{OD}	Differential output voltage magnitude	$R_L = 100 \Omega$,	See Figure 1	2	3.1		V
$\Delta V_{OD} $	Change in magnitude of differential output voltage ⁽²⁾	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
Voc	Common-mode output voltage	$R_L = 100 \Omega$,	See Figure 1			3	V
$\Delta V_{OC} $	Change in magnitude of common-mode output voltage (2)	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
I	Input current	$V_I = V_{CC}$ or GN	D			±1	μA
	Driver entent entrest with power off	V 0	V _O = 6 V			100	
I _{O(off)}	Driver output current with power off	$V_{CC} = 0$	$V_{O} = -0.25 \text{ V}$			-100	μA
Ios	Driver output short-circuit current	$V_O = 0$		-30		-150	mA
	High impedance off state output ourrent	V _O = 2.5 V				20	
I _{OZ}	High-impedance off-state output current	V _O = 0.5 V				-20	μA
			V _I = 0 or 5 V			100	μA
I _{CC}	Quiescent supply current	I _O = 0	V _I = 2.4 V or 0.5 V ⁽³⁾		1.5	3	mA
Ci	Input capacitance				6		pF

⁽¹⁾

SWITCHING CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS		AM26C31C AM26C31I				
				MIN	TYP ⁽¹⁾	MAX			
t _{PLH}	Propagation delay time, low-to-high-level output	C1 is onen	Coo Figure 2	3	7	12			
t _{PHL}	Propagation delay time, high-to-low-level output	S1 is open,	See Figure 2	3	7	12	ns		
t _{sk(p)}	Pulse skew time (t _{PLH} - t _{PHL})	S1 is open,	See Figure 2		0.5	4	ns		
$t_{r(OD)}, t_{f(OD)}$	Differential output rise and fall times	S1 is open,	See Figure 3		5	10	ns		
t _{PZH}	Output enable time to high level	C1 is slessed	Coo Figure 4		10	19			
t_{PZL}	Output enable time to low level	S1 is closed,	See Figure 4		10	19	ns		
t _{PHZ}	Output disable time from high level	C4 is slessed	Can Figure 4		7	16			
t _{PLZ}	Output disable time from low level	S1 is closed,	See Figure 4		7	16	ns		
C _{pd}	Power dissipation capacitance (each driver) ⁽²⁾	S1 is open,	See Figure 2		170		pF		

All typical values are at V_{CC} = 5 V and T_A = 25°C. $\Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level

This parameter is measured per input. All other inputs are at 0 or 5 V.

⁽¹⁾ All typical values are at $V_{CC} = 5$ V and $T_A = 25$ °C. (2) C_{pd} is used to estimate the switching losses according to $P_D = C_{pd} \times V_{CC}^2 \times f$, where f is the switching frequency.



ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST (CONDITIONS	A A	UNIT		
				MIN	TYP ⁽¹⁾	MAX	
V_{OH}	High-level output voltage	$I_O = -20 \text{ mA}$		2.2	3.4		V
V_{OL}	Low-level output voltage	I _O = 20 mA			0.2	0.4	V
V _{OD}	Differential output voltage magnitude	$R_L = 100 \Omega$,	See Figure 1	2	3.1		V
$\Delta V_{OD} $	Change in magnitude of differential output voltage ⁽²⁾	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
Voc	Common-mode output voltage	$R_L = 100 \Omega$,	See Figure 1			3	V
Δ V _{OC}	Change in magnitude of common-mode output voltage (2)	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
II	Input current	$V_I = V_{CC}$ or GN	D			±1	μΑ
	Daire a start a mark with a sure off	V 0	V _O = 6 V			100	
I _{O(off)}	Driver output current with power off	$V_{CC} = 0$	V _O = -0.25 V			-100	μA
Ios	Driver output short-circuit current	V _O = 0				-170	mA
	High immediates off state output surrent	V _O = 2.5 V				20	
I _{OZ}	High-impedance off-state output current	V _O = 0.5 V				-20	μA
			V _I = 0 or 5 V			100	μΑ
I _{CC}	Quiescent supply current	I _O = 0	V _I = 2.4 V or 0.5 V ⁽³⁾			3.2	mA
Ci	Input capacitance				6		pF

⁽¹⁾

SWITCHING CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS		AM26C31Q AM26C31M				
				MIN	TYP ⁽¹⁾	YP ⁽¹⁾ MAX			
t _{PLH}	Propagation delay time, low-to-high-level output	C1 is onen	Coo Figure 2		7	12			
t _{PHL}	Propagation delay time, high-to-low-level output	S1 is open,	See Figure 2		6.5	12	ns		
t _{sk(p)}	Pulse skew time (t _{PLH} - t _{PHL})	S1 is open,	See Figure 2		0.5	4	ns		
$t_{r(OD)}, t_{f(OD)}$	Differential output rise and fall times	S1 is open,	See Figure 3		5	12	ns		
t _{PZH}	Output enable time to high level	C1 is slessed	Coo Figure 4		10	19			
t_{PZL}	Output enable time to low level	S1 is closed,	See Figure 4		10	19	ns		
t _{PHZ}	Output disable time from high level	C1 is slessed	Coo Figure 4		7	16			
t _{PLZ}	Output disable time from low level	S1 is closed,	See Figure 4		7	16	ns		
C _{pd}	Power dissipation capacitance (each driver) (2)	S1 is open,	See Figure 2		100		pF		

All typical values are at V_{CC} = 5 V and T_A = 25°C. $\Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level

This parameter is measured per input. All other inputs are at 0 or 5 V.

⁽¹⁾ All typical values are at $V_{CC} = 5$ V and $T_A = 25$ °C. (2) C_{pd} is used to estimate the switching losses according to $P_D = C_{pd} \times V_{CC}^2 \times f$, where f is the switching frequency.



PARAMETER MEASUREMENT INFORMATION

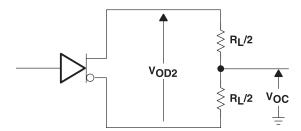
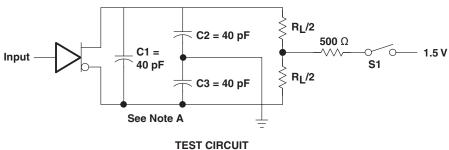


Figure 1. Differential and Common-Mode Output Voltages

- A. C1, C2, and C3 include probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, and $t_{\rm f}$, $t_{\rm f} \leq$ 6 ns.



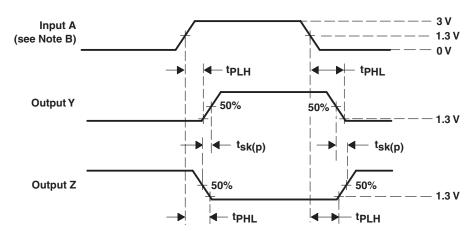


Figure 2. Propagation Delay Time and Skew Waveforms and Test Circuit

- A. C1, C2, and C3 include probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, and t_r , $t_f \leq$ 6 ns.



PARAMETER MEASUREMENT INFORMATION (continued)

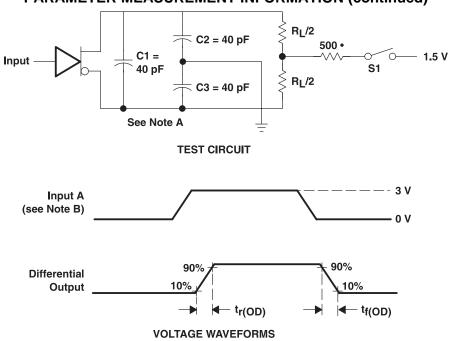
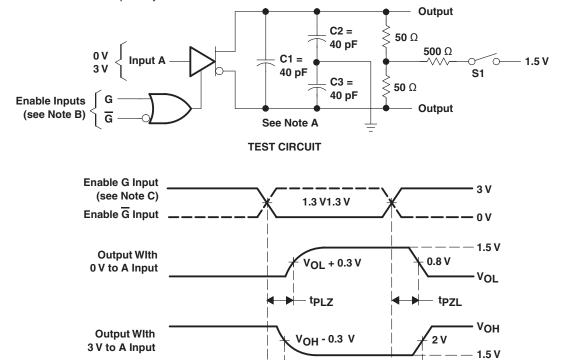


Figure 3. Differential-Output Rise- and Fall-Time Waveforms and Test Circuit

- A. C1, C2, and C3 include probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, duty cycle ≤ 50%, and t_r, t_f ≤ 6 ns.
- C. Each enable is tested separately.



VOLTAGE WAVEFORMS

Figure 4. Output Enable- and Disable-Time Waveforms and Test Circuit

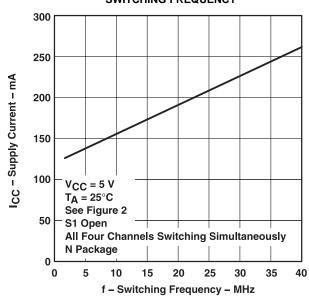
- tPHZ



TYPICAL CHARACTERISTICS

SUPPLY CURRENT

SWITCHING FREQUENCY





REVISION HISTORY

Cł	changes from Revision M (June 2008) to Revision N	Page
•	Changed units to mA from µA to fix units typo.	





18-Oct-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9163901M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9163901M2A AM26C31M	Sample
5962-9163901MEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901ME A AM26C31M	Sample
5962-9163901MFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901MF A AM26C31M	Sample
5962-9163901Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9163901Q2A AM26C31 MFKB	Sample
5962-9163901QEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QE A AM26C31MJB	Sample
5962-9163901QFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QF A AM26C31MWB	Sample
AM26C31CD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Sample
AM26C31CDBLE	OBSOLETE	SSOP	DB	16		TBD	Call TI	Call TI	0 to 70		
AM26C31CDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Sample
AM26C31CDBRE4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Sample
AM26C31CDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Sample
AM26C31CDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Sample
AM26C31CDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Sample
AM26C31CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Sample





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Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
AM26C31CDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AM26C31C	Samples
AM26C31CN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	AM26C31CN	Samples
AM26C31CNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	AM26C31CN	Samples
AM26C31CNSR	ACTIVE	so	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CNSRE4	ACTIVE	so	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31CNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	26C31	Samples
AM26C31ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDBLE	OBSOLETI	E SSOP	DB	16		TBD	Call TI	Call TI	-40 to 85		
AM26C31IDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IDBRE4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AM26C31I	Samples
AM26C31IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	AM26C31IN	Samples





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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
AM26C31INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	AM26C31IN	Samples
AM26C31INSR	ACTIVE	so	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31INSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	26C31I	Samples
AM26C31MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9163901Q2A AM26C31 MFKB	Samples
AM26C31MJB	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QE A AM26C31MJB	Samples
AM26C31MWB	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9163901QF A AM26C31MWB	Samples
AM26C31QD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AM26C31Q	Samples
AM26C31QDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26C31Q	Samples
AM26C31QDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AM26C31Q	Samples
AM26C31QDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26C31Q	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

PACKAGE OPTION ADDENDUM



18-Oct-2013

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF AM26C31, AM26C31M:

Catalog: AM26C31

Enhanced Product: AM26C31-EP, AM26C31-EP

Military: AM26C31M





18-Oct-2013

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Oct-2013

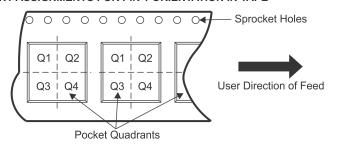
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AM26C31CDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
AM26C31CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
AM26C31IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IDR	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
AM26C31QDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26C31QDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

www.ti.com 5-Oct-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
AM26C31CDBR	SSOP	DB	16	2000	367.0	367.0	38.0	
AM26C31CDR	SOIC	D	16	2500	333.2	345.9	28.6	
AM26C31IDBR	SSOP	DB	16	2000	367.0	367.0	38.0	
AM26C31IDR	SOIC	D	16	2500	333.2	345.9	28.6	
AM26C31IDR	SOIC	D	16	2500	364.0	364.0	27.0	
AM26C31IDRG4	SOIC	D	16	2500	333.2	345.9	28.6	
AM26C31IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0	
AM26C31QDR	SOIC	D	16	2500	367.0	367.0	38.0	
AM26C31QDRG4	SOIC	D	16	2500	333.2	345.9	28.6	

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F16 and JEDEC MO-092AC



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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